

DATA SHEET



N-Channel Silicon MOSFET - General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- 2.5V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	۱ _D		1.5	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	6	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² ×0.8mm)	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	VDS=10V, ID=800mA	1.3	2.2		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=800mA, VGS=4V		165	215	mΩ
	R _{DS} (on)2	ID=400mA, VGS=2.5V		210	295	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		130		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		22		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		16		pF

Marking : LF

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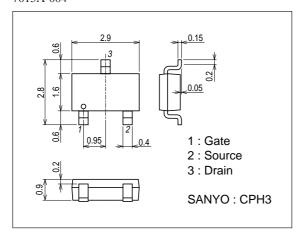
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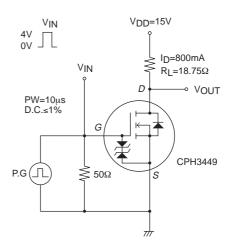
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		9		ns
Rise Time	tr	See specified Test Circuit.		20		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		23		ns
Fall Time	tf	See specified Test Circuit.		29		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4V, I _D =1.5A		2.2		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4V, I _D =1.5A		0.52		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4V, I _D =1.5A		0.52		nC
Diode Forward Voltage	V _{SD}	IS=1.5A, VGS=0V		0.9	1.2	V

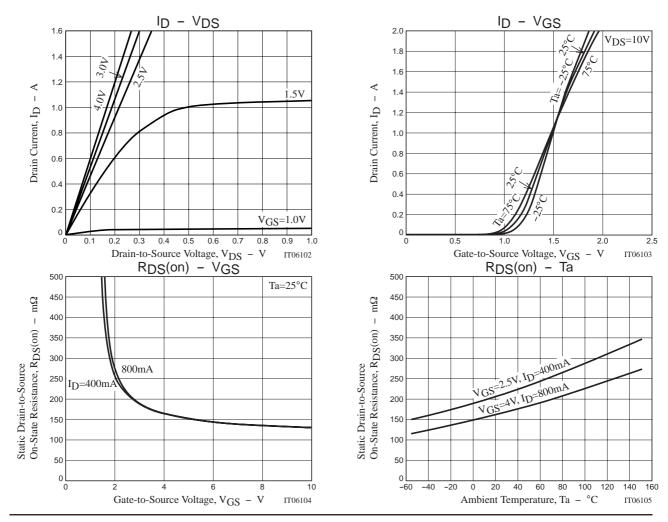
Package Dimensions

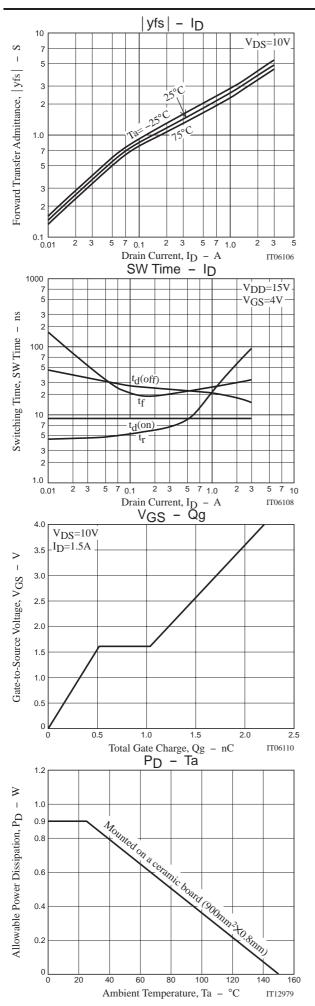
unit : mm (typ) 7015A-004

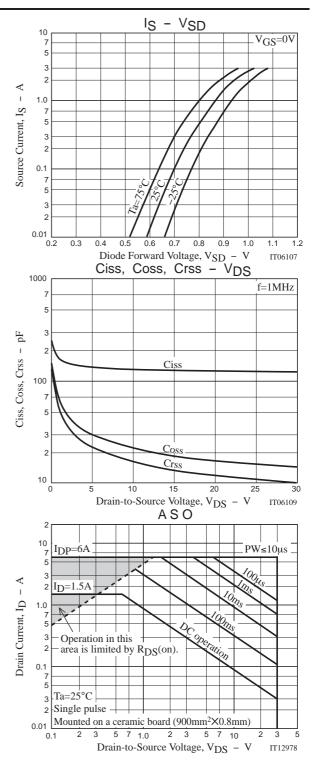


Switching Time Test Circuit









Note on usage : Since the CPH3449 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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